HMC308 / 308E

GENERAL PURPOSE 100 mW GaAs MMIC AMPLIFIER, 0.8 - 3.8 GHz

Typical Applications

Broadband or Narrow Band Applications:

- Cellular/PCS/3G
- Fixed Wireless & Telematics
- Cable Modem Termination Systems
- WLAN, Bluetooth & RFID

Features

Gain: 18 dB

P1dB Output Power: +17 dBm@ +5V

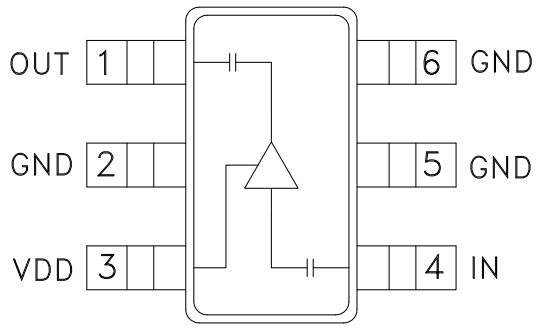
Single Supply: +3V or +5V

No External Components

Integrated DC Blocks

Ultra Small Package: SOT26

Functional Diagram



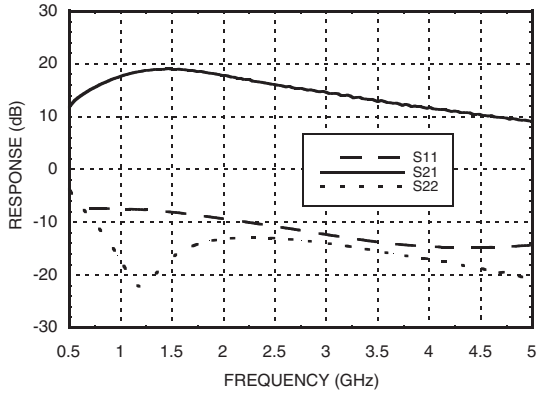
General Description

The HMC308 & HMC308E are low cost MESFET MMIC amplifiers that operate from a single +3 to +5V supply from 0.8 to 3.8 GHz. The surface mount SOT26 amplifier can be used as a broadband amplifier stage or used with external matching for optimized narrow band applications. With Vdd biased at +5V, the HMC308 & HMC308E offers 18 dB of gain and +20 dBm of saturated output power while requiring only 53 mA of current. This amplifier is ideal as a driver amplifier for transmitters or for use as a local oscillator (LO) amplifier to increase drive levels for passive mixers. The amplifier occupies 0.014 in^2 (9 mm^2), making it ideal for compact radio designs.

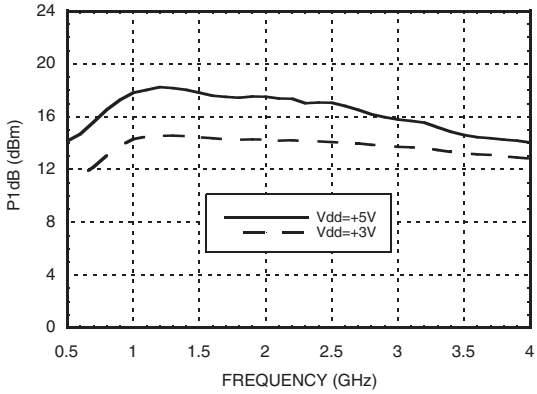
Electrical Specifications, T_A = +25° C, as a function of Vdd

Parameter	Vdd = +3V			Vdd = +5V			Vdd = +5V			Vdd = +5V			Units
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
Frequency Range	2.3 - 2.7			0.8 - 2.3			2.3 - 2.7			2.7 - 3.8			GHz
Gain	13	15.5		14	18		13	16		10	13		dB
Gain Variation over Temperature		0.025	0.035		0.025	0.035		0.025	0.035		0.025	0.035	dB/°C
Input Return Loss		11			8			11			13		dB
Output Return Loss		17			13			12			13		dB
Output Power for 1 dB Compression (P1dB)	12	14		14	17		13.5	16.5		12	15		dBm
Saturated Output Power (Psat)		17			20			19.5			17		dBm
Output Third Order Intercept (IP3)	23	26		27	30		26	29		24	27		dBm
Noise Figure		7			7.5			7			7		dB
Supply Current (Idd)		50			53			53			53		mA

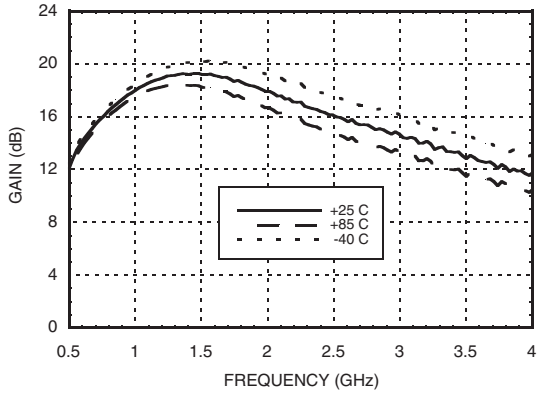
Broadband Gain & Return Loss @ Vdd = +5V



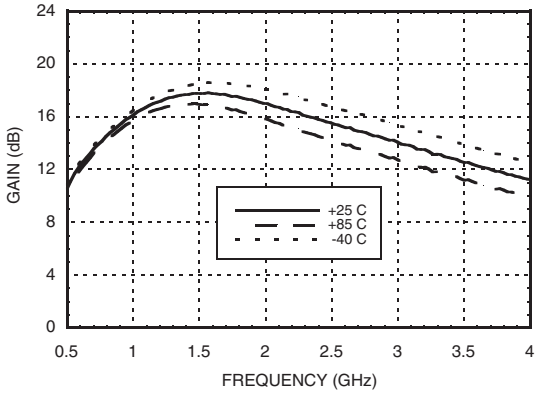
P1dB vs. Vdd Bias



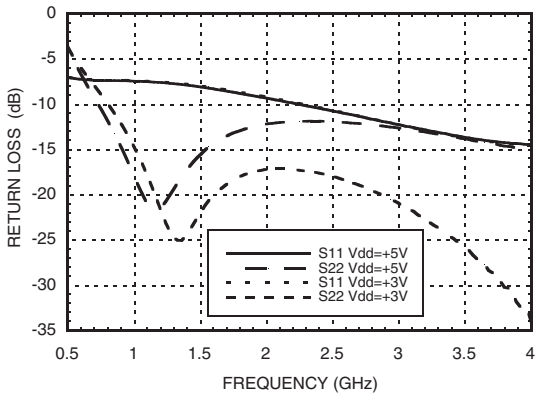
Gain vs. Temperature @ Vdd = +5V



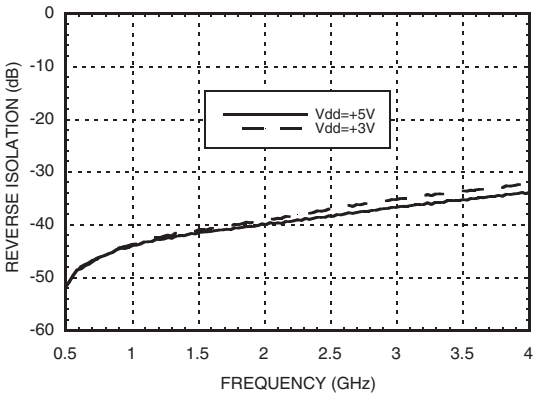
Gain vs. Temperature @ Vdd = +3V



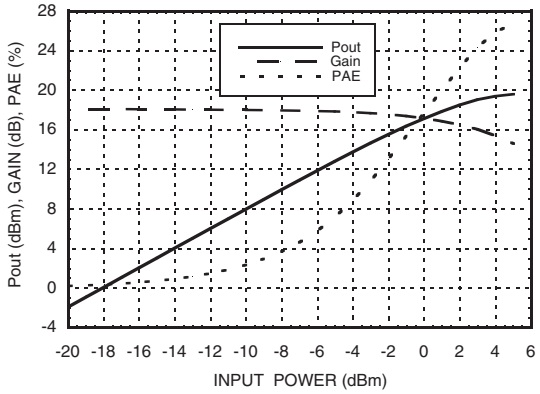
Input & Output Return Loss vs. Vdd Bias



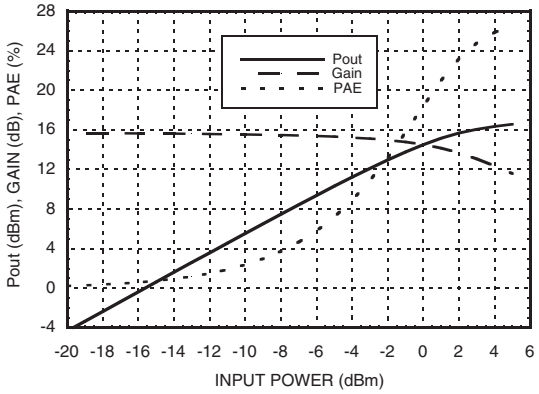
Reverse Isolation vs. Vdd Bias



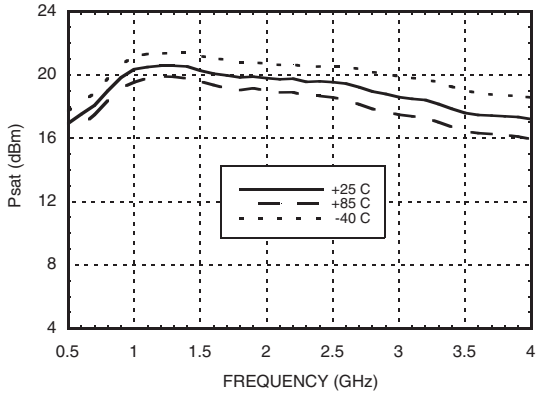
Power Compression @ 2.0 GHz, Vdd = +5V



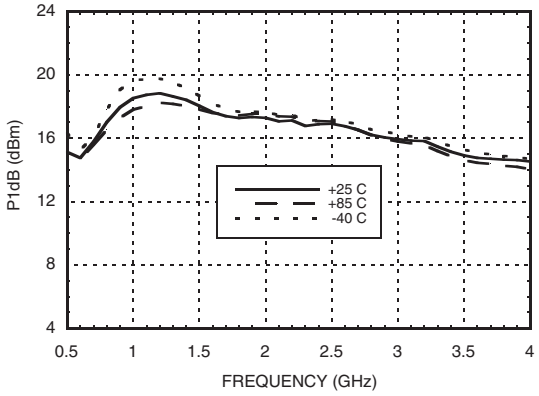
Power Compression @ 2.5 GHz, Vdd = +5V



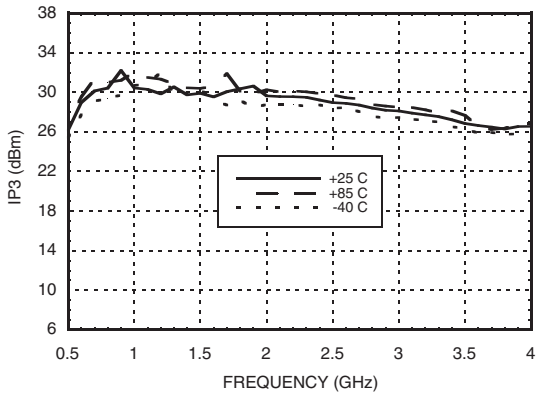
Psat vs. Temperature @ Vdd = +5V



Output P1dB vs. Temperature @ Vdd = +5V



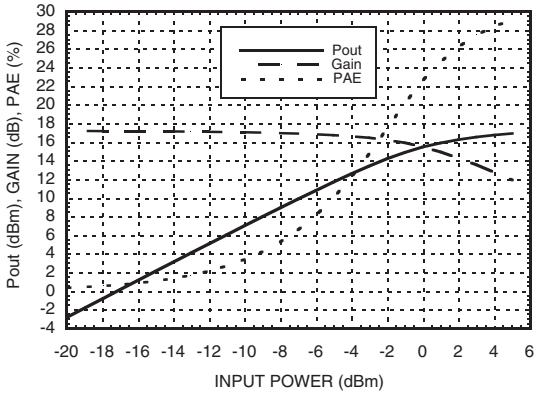
Output IP3 vs. Temperature @ Vdd = +5V



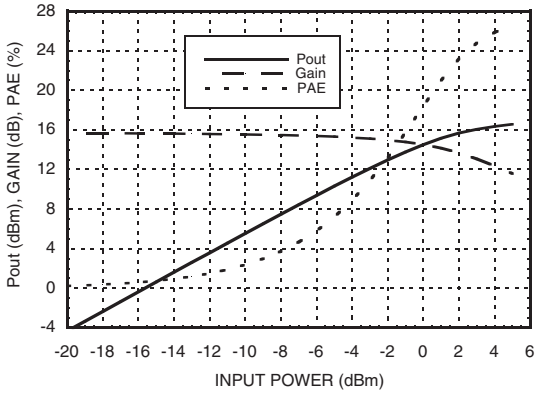
Typical Supply Current vs. Vdd

Vdd (Vdc)	Idd (mA)
+2.5	49
+3.0	50
+3.5	51
+4.5	50
+5.0	53
+5.5	54

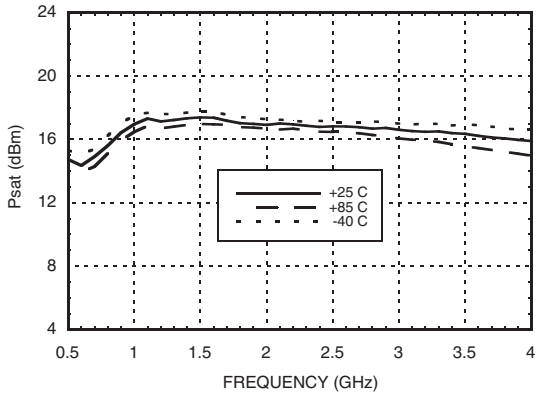
Power Compression @ 2.0 GHz, Vdd = +3V



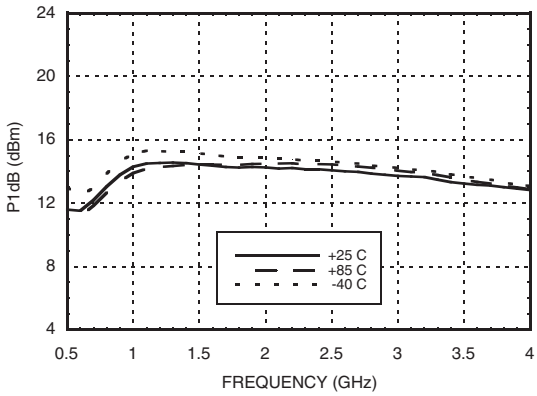
Power Compression @ 2.5 GHz, Vdd = +3V



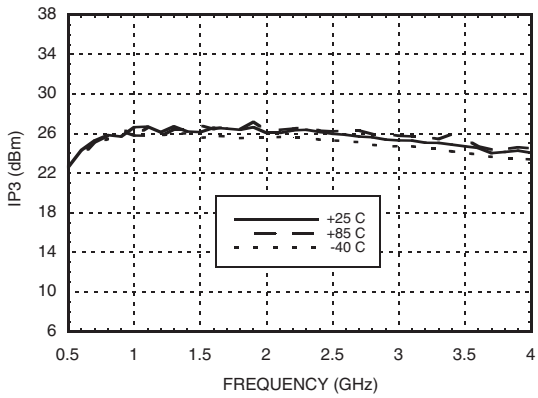
Psat vs. Temperature @ Vdd = +3V



Output P1dB vs. Temperature @ Vdd = +3V



Output IP3 vs. Temperature @ Vdd = +3V

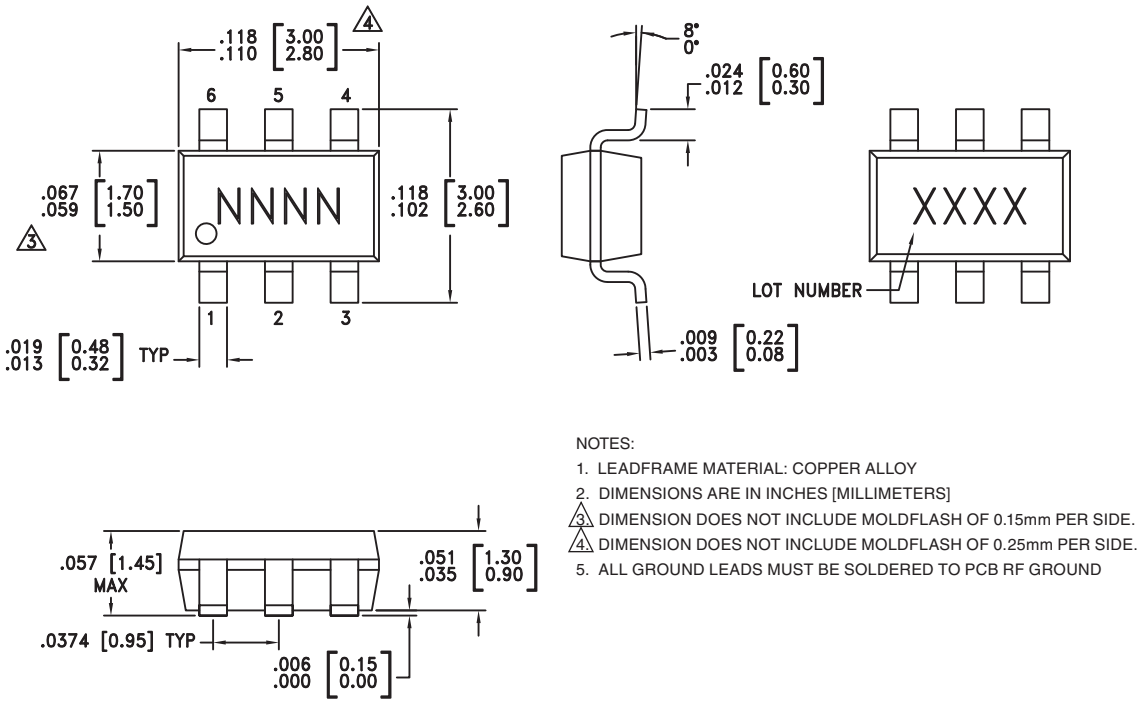


Absolute Maximum Ratings

Drain Bias Voltage (Vdd)	+7.0 Vdc
RF Input Power (RFIN)(Vdd = +5Vdc)	+10 dBm
Channel Temperature	150 °C
Continuous Pdiss (T = 85 °C) (derate 6.25 mW/°C above 85 °C)	0.406 W
Thermal Resistance (channel to lead)	160 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A

ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing



NOTES:

1. LEADFRAME MATERIAL: COPPER ALLOY
2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
3. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
4. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
5. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND

Package Information

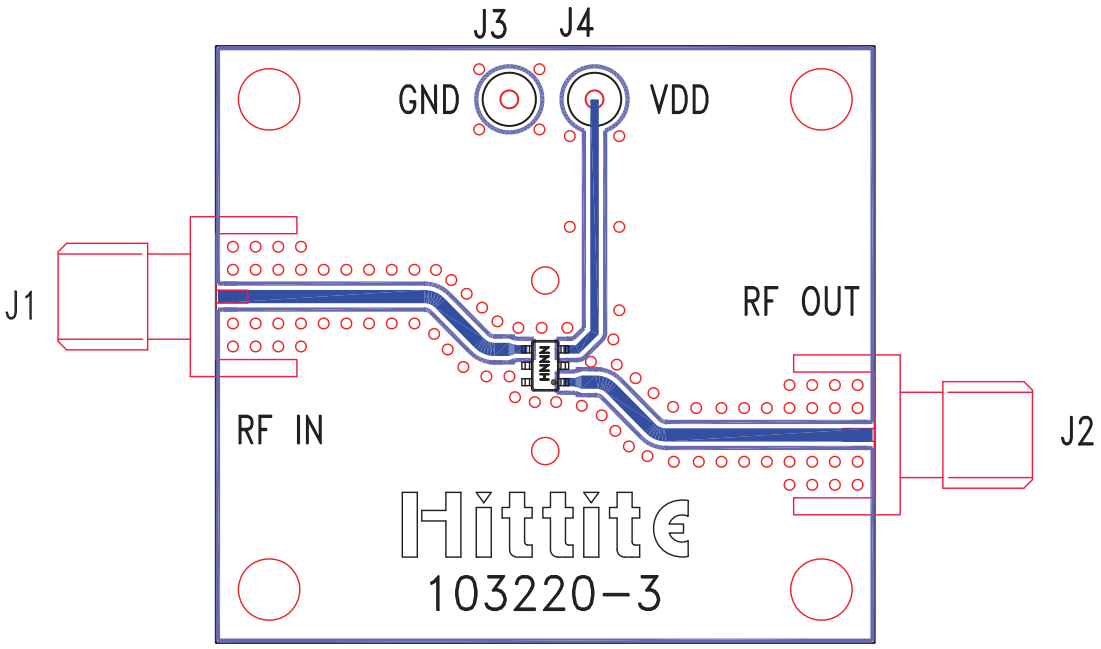
Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC308	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H308 XXXX
HMC308E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	308E XXXX

[1] Max peak reflow temperature of 235 °C
[2] Max peak reflow temperature of 260 °C
[3] 4-Digit lot number XXXX

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	RFOUT	This pin is AC coupled and matched to 50 Ohms.	RFOUT
2, 5, 6	GND	These pins must be connected to RF/DC ground.	GND
3	Vdd	Power supply voltage.	Vdd
4	RFIN	This pin is AC coupled and matched to 50 Ohms.	RFIN

Evaluation PCB



List of Materials for Evaluation PCB 103802 [1]

Item	Description
J1, J2	PCB Mount SMA Connector
J3, J4	DC Pins
U1	HMC308 / HMC308E Amplifier
PCB [2]	103220 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Roger 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.